

| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|-------|------|---|---|------------------|---------|------------------|
| L1 | 2575 | (antifuse or antifusing or antifusible or anti-fuse or anti-fusing or anti-fusible) same (drain or gate or mos or mosfet or transistor or fet) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/02/11 08:39 |
| L2 | 15 | (antifuse or antifusing or antifusible or anti-fuse or anti-fusing or anti-fusible) same (drain or gate or mos or mosfet or transistor or fet) same (idd or (source or drain) near2 extension) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/02/11 08:53 |
| L7 | 131 | (antifuse or antifusing or antifusible or anti-fuse or anti-fusing or anti-fusible) near10 (gate near2 (dielectric or oxide)) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/02/11 09:58 |
| L9 | 392 | (antifuse or antifusing or antifusible or anti-fuse or anti-fusing or anti-fusible) and (source) near2 (drain) near2 (overlap or overlapping or overlapped or joining or joined or connected or connecting or connection) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/02/11 10:18 |
| L10 | 68 | (antifuse or antifusing or antifusible or anti-fuse or anti-fusing or anti-fusible) and (channel) near2 (idd or doped) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/02/11 10:24 |
| L11 | 32 | (antifuse or antifusing or antifusible or anti-fuse or anti-fusing or anti-fusible) and (source or drain) near2 (path or conduit or short or shorting or shorted or interconnect or connection) near2 (channel or well) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/02/11 10:35 |
| L12 | 59 | (antifuse or antifusing or antifusible or anti-fuse or anti-fusing or anti-fusible) and (channel) near2 (narrow or small) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/02/11 10:42 |
| L14 | 1266 | (mos or mosfet or fet or nmos or pmos or cmos or misfet or mesfet) and ((source) near2 (overlapping or overlapped or overlap or touching) near2 drain) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/02/11 10:48 |
| L15 | 611 | (mos or mosfet or fet or nmos or pmos or cmos or misfet or mesfet) and ((source) near (overlapping or overlapped or overlap or touching) near drain) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/02/11 10:49 |
| L16 | 12 | (mos or mosfet or fet or nmos or pmos or cmos or misfet or mesfet) and ((source) near (overlapping or overlapped or overlap or touching) near drain) near10 ldd | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/02/11 10:49 |